
HL6714G

AlGalnP Laser Diode

HITACHI

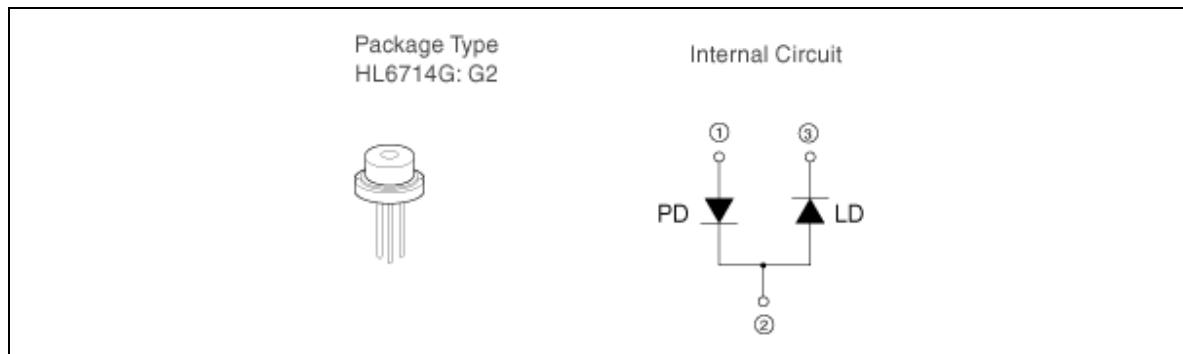
Literature Order Number
Rev 0
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Description

The HL6714G is a 0.67 μm band AlGaInP index-guided laser diode with a multi-quantum well(MQW)structure. It is suitable as a light source for laser beam printers, levelers and various other types of optical equipment. Hermetic sealing of the package assures high reliability.

Features

- Visible light output at wavelengths up to 680 nm
- Single longitudinal mode
- Low astigmatism: 10 μm Typ
- High output power: 10 mW (CW)
- Built-in monitor photodiode



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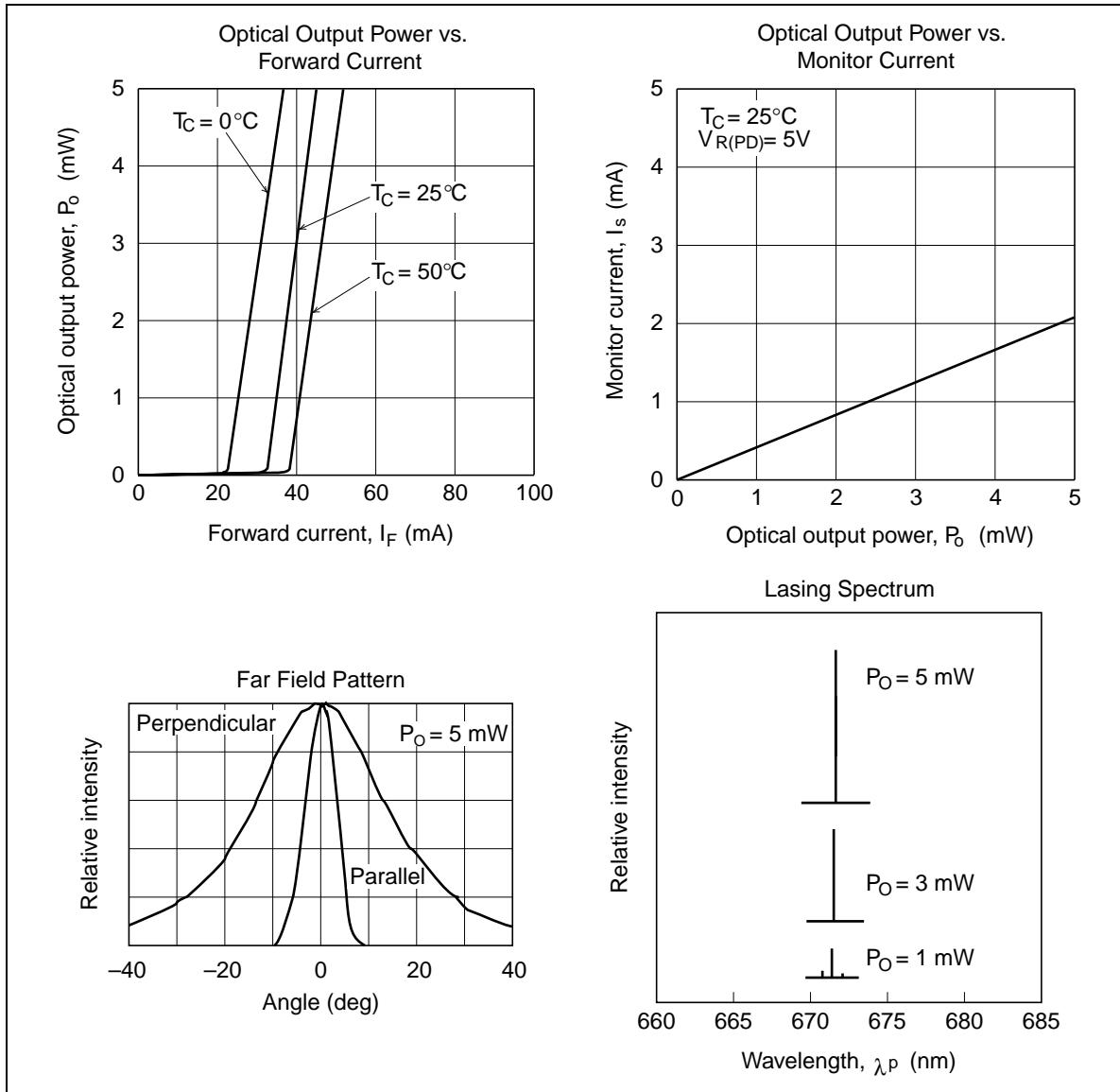
Absolute Maximum Ratings ($T_c = 25^\circ\text{C}$)

| Item | Symbol | Rated Value | Unit |
|----------------------------|---------------|------------------|------|
| Optical output power | P_o | 10 | mW |
| Pulse optical output power | P_o (pulse) | 12* ¹ | mW |
| LD reverse voltage | V_R (LD) | 2 | V |
| PD reverse voltage | V_R (PD) | 30 | V |
| Operating temperature | T_{opr} | -10 to +50 | °C |
| Storage temperature | T_{stg} | -40 to +85 | °C |

Note: 1. Maximum 50% duty cycle, maximum 1 μs pulse width

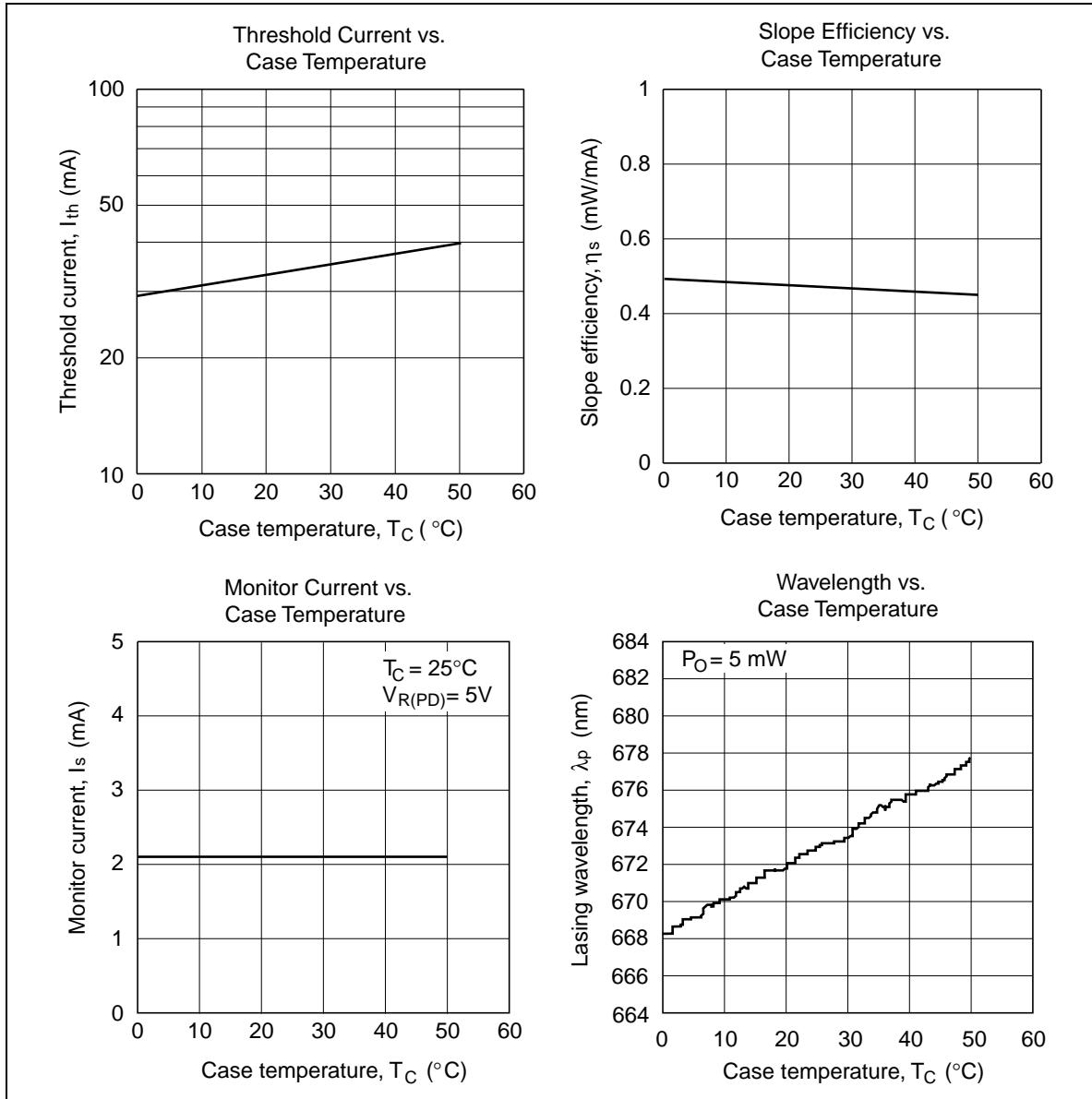
Optical and Electrical Characteristics ($T_c = 25^\circ\text{C}$)

| Item | Symbol | Min | Typ | Max | Unit | Test Conditions |
|---------------------------------|------------------|-----|-----|-----|---------------|--|
| Optical output power | P_o | 10 | — | — | mW | Kink free |
| Threshold current | I_{th} | 20 | 35 | 60 | mA | |
| Slope efficiency | η | 0.3 | 0.5 | 0.8 | mW/mA | $6 \text{ (mW)} / I_{(8 \text{ mW})} - I_{(2 \text{ mW})}$ |
| LD Operating Voltage | V_{op} | — | — | 2.7 | V | $P_o = 10 \text{ mW}$ |
| Lasing wavelength | λ_p | 660 | 670 | 680 | nm | $P_o = 10 \text{ mW}$ |
| Beam divergence (parallel) | $\theta_{ }$ | 5 | 8 | 11 | deg. | $P_o = 10 \text{ mW}, \text{FWHM}$ |
| Beam divergence (perpendicular) | θ_{\perp} | 18 | 22 | 30 | deg. | $P_o = 10 \text{ mW}, \text{FWHM}$ |
| Monitor current | I_s | 0.3 | 0.8 | 1.5 | mA | $P_o = 10 \text{ mW}, V_{(PD)} = 5 \text{ V}$ |
| Astigmatism | A_s | — | 10 | — | μm | $P_o = 10 \text{ mW}, \text{NA} = 0.55$ |

Typical Characteristic Curves

HL6714G

Typical Characteristic Curves (cont)



Typical Characteristic Curves (cont)